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MOSFETs Silicon N-channel MOS (U-MOSⅧ-H)

TPH2R608NH

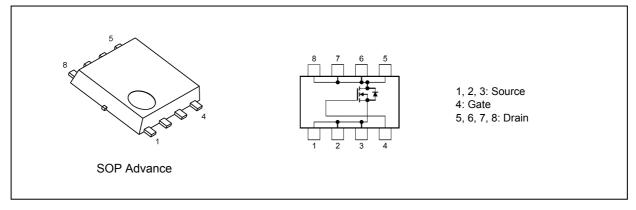
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 28 \text{ nC}$ (typ.)
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 2.1 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (4) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 75 \ V)$
- (5) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1.0 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25 \ ^{\circ}C$ unless otherwise specified)

Characterist	tics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	75	V
Gate-source voltage			V _{GSS}	±20]
Drain current (DC)		(Note 1)	Ι _D	150	A
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	Ι _D	168	A
Drain current (pulsed)	(t = 100 μs)	(Note 1)	I _{DP}	500	A
Power dissipation	(T _c = 25 °C)		PD	142	W
Power dissipation		(Note 3)	PD	2.5	W
Power dissipation		(Note 4)	PD	0.8	W
Single-pulse avalanche energy		(Note 5)	E _{AS}	149	mJ
Single-pulse avalanche current		(Note 5)	I _{AS}	120	A
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2015-01

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit		
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	0.88	°C/W
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 3)	R _{th(ch-a)}	50	
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 4)	R _{th(ch-a)}	156	

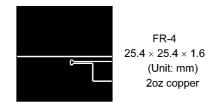
Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Limited by package limit. Silicon chip capability is 168 A. ($T_c = 25 \text{ °C}$)

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: V_DD = 60 V, T_ch = 25 °C (initial), L = 0.008 mH, I_{AS} = 120 A



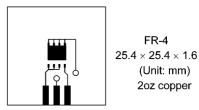


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a) Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 75 V, V _{GS} = 0 V			10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	75	_	_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	55		_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1.0 mA	2.0		4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 50 A	_	2.1	2.6	mΩ

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V_{DS} = 37.5 V, V_{GS} = 0 V, f = 1 MHz	_	4600	6000	pF
Reverse transfer capacitance	C _{rss}		_	50	95	
Output capacitance	C _{oss}			1100	_	
Gate resistance	rg	—	_	1.0	1.5	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	11	_	ns
Switching time (turn-on time)	t _{on}			30	_	
Switching time (fall time)	t _f			15	_	
Switching time (turn-off time)	t _{off}		_	56	_	

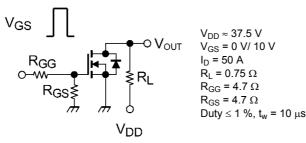


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

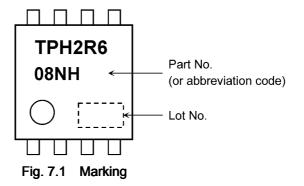
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD}\approx 37.5 \text{ V}, \text{ V}_{GS} \text{ = } 10 \text{ V}, \text{ I}_{D} \text{ = } 50 \text{ A}$	—	72	—	nC
Gate-source charge 1	Q _{gs1}		_	24	_	
Gate-drain charge	Q _{gd}		_	18	_	
Gate switch charge	Q _{SW}			28	_	

6.4. Source-Drain Characteristics (Ta = 25 °C unless otherwise specified)

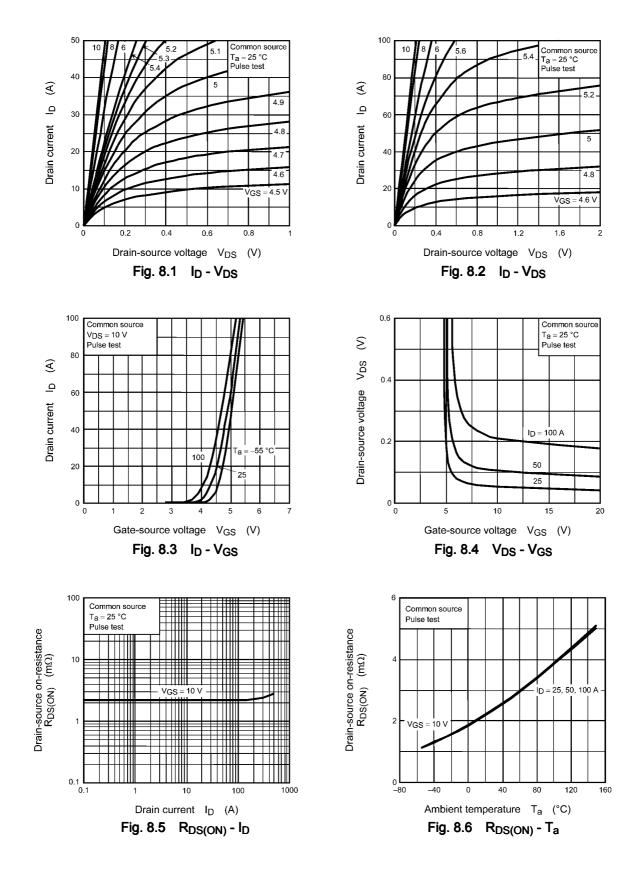
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 6)	—	—	_	500	A
Diode forward voltage	V _{DSF}	I _{DR} = 150 A, V _{GS} = 0 V	_	_	-1.2	V

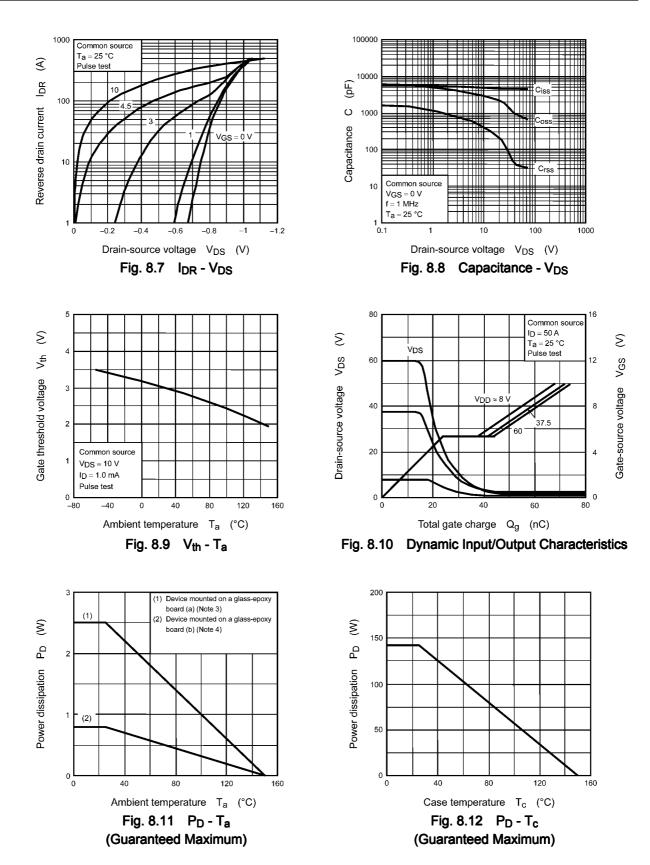
Note 6: Ensure that the channel temperature does not exceed 150 °C.

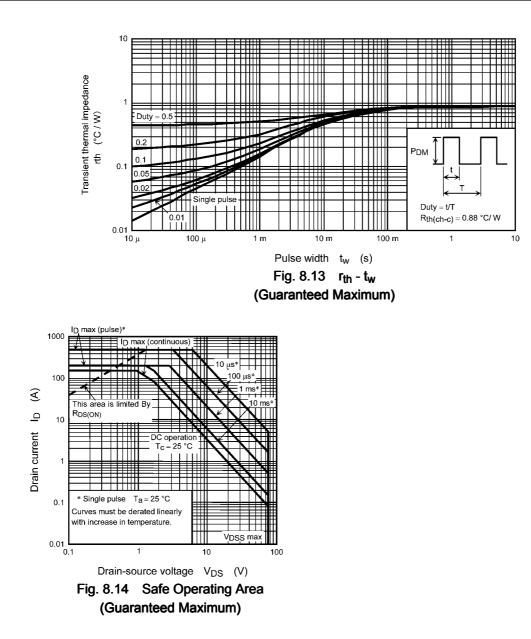
7. Marking



8. Characteristics Curves (Note)



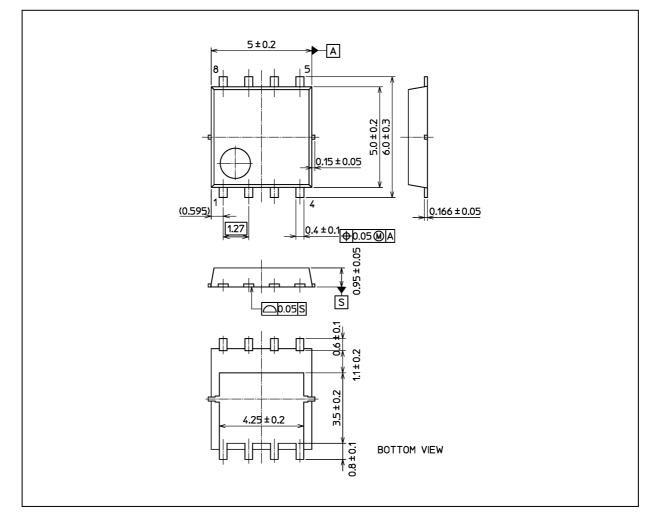




Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)	
TOSHIBA: 2-5Q1S	
Nickname: SOP Advance	

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